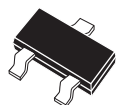


CMPSH05-4
SURFACE MOUNT
HIGH CURRENT, LOW V_F
SILICON SCHOTTKY DIODE



SOT-23 CASE

MARKING CODE: C054

MAXIMUM RATINGS: ($T_A=25^{\circ}\text{C}$)

	SYMBOL		UNITS
Peak Repetitive Reverse Voltage	V_{RRM}	40	V
Continuous Forward Current	I_F	500	mA
Peak Repetitive Forward Current, $t_p \leq 1\text{ms}$	I_{FRM}	3.5	A
Forward Surge Current, $t_p=8\text{ms}$	I_{FSM}	10	A
Power Dissipation	P_D	350	mW
Operating and Storage			
Junction Temperature	T_J, T_{stg}	-65 to +150	$^{\circ}\text{C}$
Thermal Resistance	θ_{JA}	357	$^{\circ}\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_R	$V_R=10\text{V}$		20	μA
I_R	$V_R=30\text{V}$		100	μA
BV_R	$I_R=500\mu\text{A}$	40		V
V_F	$I_F=100\mu\text{A}$		0.13	V
V_F	$I_F=1.0\text{mA}$		0.21	V
V_F	$I_F=10\text{mA}$		0.27	V
V_F	$I_F=100\text{mA}$		0.35	V
V_F	$I_F=500\text{mA}$		0.47	V
C_T	$V_R=1.0\text{V}, f=1.0\text{MHz}$		50	pF

CentralTM
Semiconductor Corp.

DESCRIPTION:

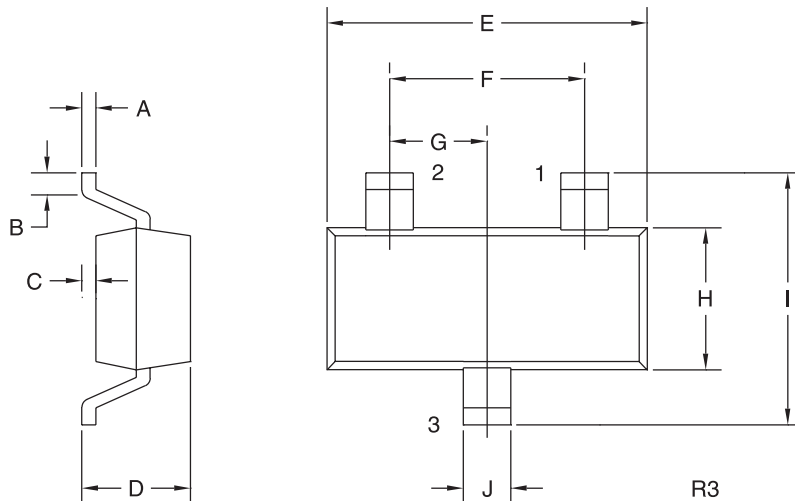
The CENTRAL SEMICONDUCTOR CMPSH05-4 is a HIGH CURRENT, LOW V_F 40 volt Schottky Diode packaged in a space saving SOT-23 surface mount case. This device has been designed for small signal general purpose applications when small size and operational efficiency are prime requirements.

SPECIFICATIONS:

- Low $V_F = 0.35\text{V}$ max @ 100mA
- $V_{RRM} = 40\text{V}$
- $I_F = 500\text{mA}$

R0 (13-September 2004)

SOT-23 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) ANODE
- 2) N/C
- 3) CATHODE

MARKING CODE: C054

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.003	0.007	0.08	0.18
B	0.006	-	0.15	-
C	-	0.005	-	0.13
D	0.035	0.043	0.89	1.09
E	0.110	0.120	2.80	3.05
F	0.075		1.90	
G	0.037		0.95	
H	0.047	0.055	1.19	1.40
I	0.083	0.098	2.10	2.49
J	0.014	0.020	0.35	0.50

SOT-23 (REV: R3)